## : ©hipsmall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation, and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!


## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email \& Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, \#122 Zhenhua RD., Futian, Shenzhen, China

## GigaMOS ${ }^{\text {TM }}$

Power MOSFET

N-Channel Enhancement Mode
Avalanche Rated
Fast Intrinsic Diode
IXFK170N20T IXFX170N20T


| Symbol | Test Conditions | Maximum Ratings |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {DSS }}$ | $\mathrm{T}_{J}=25^{\circ} \mathrm{C}$ to $175^{\circ} \mathrm{C}$ | 200 | V |
| $\mathrm{V}_{\text {DGR }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ to $175^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{GS}}=1 \mathrm{M} \Omega$ | 200 | V |
| $\mathrm{V}_{\text {GSS }}$ | Continuous | $\pm 20$ | V |
| $\mathrm{V}_{\text {GSM }}$ | Transient | $\pm 30$ | V |
| $\mathrm{I}_{\mathrm{D} 25}$ | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | 170 | A |
| $\mathrm{I}_{\text {L(RMS) }}$ | External Lead Current Limit | 160 | A |
| $\mathrm{I}_{\mathrm{DM}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$, Pulse Width Limited by $\mathrm{T}_{\mathrm{JM}}$ | 470 | A |
| $\mathrm{I}_{\mathrm{A}}$ | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | 40 | A |
| $\mathrm{E}_{\text {AS }}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 3 | J |
| $\mathrm{P}_{\mathrm{D}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 1150 | W |
| dV/dt | $\mathrm{I}_{\mathrm{S}} \leq \mathrm{I}_{\mathrm{DM}}, \mathrm{V}_{\mathrm{DD}} \leq \mathrm{V}_{\mathrm{DSS}}, \mathrm{T}_{\mathrm{J}} \leq 175^{\circ} \mathrm{C}$ | 20 | $\mathrm{V} / \mathrm{ns}$ |
| $\mathrm{T}_{\mathrm{J}}$ |  | $-55 \ldots+175$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {JM }}$ |  | 175 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ |  | $-55 \ldots+175$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | 1.6 mm (0.062 in.) from Case for 10 s | 300 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {SoLD }}$ | Plastic Body for 10s | 260 | ${ }^{\circ} \mathrm{C}$ |
| M ${ }_{\text {d }}$ | Mounting Torque (TO-264) | 1.13/10 | Nm/lb.in. |
| $\mathrm{F}_{\mathrm{c}}$ | Mounting Force (PLUS247) | 20.. $120 / 4.5 . .27$ | N/lb. |
| Weight | TO-264 | 10 | g |
|  | PLUS247 | - | g |


$\mathrm{V}_{\text {DSs }}=200 \mathrm{~V}$
$\mathrm{I}_{\mathrm{DS5}}=170 \mathrm{~A}$
$\mathrm{R}_{\mathrm{DS}(\text { (on })} \leq 11 \mathrm{~m} \Omega$
$\mathrm{t}_{\mathrm{rr}} \leq 200 \mathrm{~ns}$

TO-264 (IXFK)


PLUS247 (IXFX)

$G=$ Gate $\quad D=$ Drain $S=$ Source $\quad T A B=$ Drain

Features

- International Standard Packages
- High Current Handling Capability
- Fast Intrinsic Diode
- Avalanche Rated
- Low $\mathrm{R}_{\mathrm{DS}(\text { on })}$

Advantages

- Easy to Mount
- Space Savings
- High Power Density


## Applications

- Synchronous Recification
- DC-DC Converters
- Battery Chargers
- Switched-Mode and Resonant-Mode Power Supplies
- DC Choppers
- AC Motor Drives
- Uninterruptible Power Supplies
- High Speed Power Switching Applications



## Source-Drain Diode

| $\begin{aligned} & \text { Symbol } \quad \text { Test Conditions } \\ & \left(T_{j}=25^{\circ} \mathrm{C}\right. \text {, Unless Otherwise Specified) } \end{aligned}$ |  | Characteristic Values |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Typ. | Max. |  |
| $\mathrm{I}_{\mathrm{s}}$ | $\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}$ |  |  | 170 | A |
| $\mathrm{I}_{\text {SM }}$ | Repetitive, Pulse Width Limited by $\mathrm{T}_{\mathrm{Jm}}$ |  |  | 680 | A |
| $\mathrm{V}_{\text {sD }}$ | $\mathrm{I}_{\mathrm{F}}=60 \mathrm{~A}, \mathrm{~V}_{\text {GS }}=0 \mathrm{~V}$, Note 1 |  |  | 1.3 | V |
| $\begin{aligned} & \mathbf{t}_{\mathrm{rr}} \\ & \mathbf{Q}_{\mathrm{RM}} \\ & \mathrm{I}_{\mathrm{RM}} \end{aligned}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=80 \mathrm{~A},-\mathrm{di} / \mathrm{dt}=100 \mathrm{~A} / \mathrm{s} \\ & \mathrm{~V}_{\mathrm{R}}=75 \mathrm{~V}, \mathrm{~V}_{\mathrm{Gs}}=0 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.59 \\ & 9.80 \end{aligned}$ | 200 | ns $\mu \mathrm{C}$ A |

Note 1: Pulse Test, $\mathrm{t} \leq 300 \mu \mathrm{~s}$; Duty Cycle, $\mathrm{d} \leq 2 \%$.

## ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

TO-264 (IXFK) Outline


| Dim. | Millimeter |  | Inches |  |
| :--- | :---: | :---: | :---: | :---: |
|  | Min. | Max. | Min. | Max. |
| A | 4.82 | 5.13 | .190 | .202 |
| A1 | 2.54 | 2.89 | .100 | .114 |
| A2 | 2.00 | 2.10 | .079 | .083 |
| b | 1.12 | 1.42 | .044 | .056 |
| b1 | 2.39 | 2.69 | .094 | .106 |
| b2 | 2.90 | 3.09 | .114 | .122 |
| C | 0.53 | 0.83 | .021 | .033 |
| D | 25.91 | 26.16 | 1.020 | 1.030 |
| E | 19.81 | 19.96 | .780 | .786 |
| e | 5.46 | BSC | .215 | BSC |
| J | 0.00 | 0.25 | .000 | .010 |
| K | 0.00 | 0.25 | .000 | .010 |
| L | 20.32 | 20.83 | .800 | .820 |
| L1 | 2.29 | 2.59 | .090 | .102 |
| P | 3.17 | 3.66 | .125 | .144 |
| Q | 6.07 | 6.27 | .239 | .247 |
| Q1 | 8.38 | 8.69 | .330 | .342 |
| R | 3.81 | 4.32 | .150 | .170 |
| R1 | 1.78 | 2.29 | .070 | .090 |
| S | 6.04 | 6.30 | .238 | .248 |
| T | 1.57 | 1.83 | .062 | .072 |

PLUS $247^{\text {TM }}$ (IXFX) Outline


| Dim. | Millimeter <br> Min. |  |  |  |
| :--- | ---: | :---: | :---: | :---: |
|  | Max. | Inches <br> Min. |  | Max. |
| A | 4.83 | 5.21 | .190 | .205 |
| $\mathrm{~A}_{1}$ | 2.29 | 2.54 | .090 | .100 |
| $\mathrm{~A}_{2}$ | 1.91 | 2.16 | .075 | .085 |
| b | 1.14 | 1.40 | .045 | .055 |
| $\mathrm{~b}_{1}$ | 1.91 | 2.13 | .075 | .084 |
| $\mathrm{~b}_{2}$ | 2.92 | 3.12 | .115 | .123 |
| C | 0.61 | 0.80 | .024 | .031 |
| D | 20.80 | 21.34 | .819 | .840 |
| E | 15.75 | 16.13 | .620 | .635 |
| e | 5.45 | BSC | .215 | BSC |
| L | 19.81 | 20.32 | .780 | .800 |
| L 1 | 3.81 | 4.32 | .150 | .170 |
| Q | 5.59 | 6.20 | .220 | 0.244 |
| R | 4.32 | 4.83 | .170 | .190 |

Fig. 1. Output Characteristics @ 25으․


Fig. 3. Output Characteristics @ 150ํㅡ


Fig. 5. $\mathrm{R}_{\mathrm{DS}(\mathrm{on})}$ Normalized to $\mathrm{I}_{\mathrm{D}}=85 \mathrm{~A}$ Value vs. Drain Current


Fig. 2. Extended Output Characteristics

## @ 25ํㅡ



Fig. 4. $R_{\text {DS(on) }}$ Normalized to $I_{D}=85 A$ Value vs. Junction Temperature


Fig. 6. Drain Current vs. Case Temperature


IXFK170N20T IXFX170N20T

Fig. 7. Input Admittance


Fig. 9. Forward Voltage Drop of Intrinsic Diode


Fig. 11. Capacitance


Fig. 8. Transconductance


Fig. 10. Gate Charge


Fig. 12. Forward-Bias Safe Operating Area


IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

Fig. 13. Maximum Transient Thermal Impedance


